



NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



HMC532* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

- HMC532LP4 Evaluation Board

Documentation

Application Notes

- Determining the FM Bandwidth of a Wideband Varactor Tuned VCO

Data Sheet

- HMC532 Data Sheet

Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

Design Resources

- HMC532 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions

View all HMC532 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

* This page was dynamically generated by Analog Devices, Inc. and inserted into this data sheet. Note: Dynamic changes to the content on this page does not constitute a change to the revision number of the product data sheet. This content may be frequently modified.

THIS PAGE INTENTIONALLY LEFT BLANK

Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- VSAT Radio
- Point to Point/Multipoint Radio
- Test Equipment & Industrial Controls
- Military End-Use

Features

Pout: +14 dBm

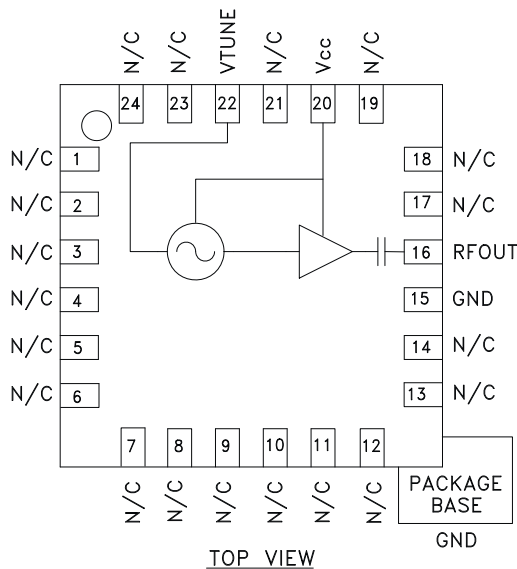
Phase Noise: -103 dBc/Hz @100 KHz

No External Resonator Needed

Single Supply: +3V @ 85 mA

24 Lead 4x4mm QFN Package: 9 mm²

Functional Diagram



General Description

The HMC532LP4 & HMC532LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 7.1 to 7.9 GHz, the VCO's phase noise performance is excellent over temperature, shock and vibration due to the oscillator's monolithic structure. Power output is +14 dBm typical from a single supply of +3V @ 85 mA. The voltage controlled oscillator is packaged in a leadless QFN 4 x 4 mm surface mount package.

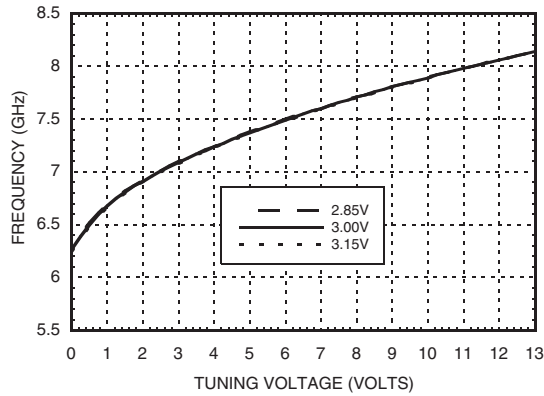
Electrical Specifications, $T_A = +25^\circ \text{C}$, $V_{CC} = +3\text{V}$

Parameter	Min.	Typ.	Max.	Units
Frequency Range	7.1 - 7.9			GHz
Power Output	12	14	17	dBm
SSB Phase Noise @ 100 kHz Offset, $V_{tune} = +5\text{V}$ @ RF Output		-101		dBc/Hz
Tune Voltage (V_{tune})	1		13	V
Supply Current (I_{CC}) ($V_{CC} = +3\text{V}$)	60	85	100	mA
Tune Port Leakage Current			10	μA
Output Return Loss		15		dB
Harmonics				
2nd		-14		dBc
3rd		-25		dBc
Pulling (into a 2.0:1 VSWR)		28		MHz pp
Pushing @ $V_{tune} = +5\text{V}$		78		MHz/V
Frequency Drift Rate		0.85		MHz/ $^\circ\text{C}$

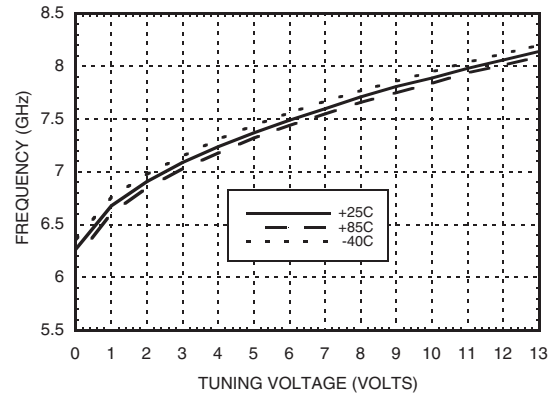
HMC532LP4 / 532LP4E

MMIC VCO w/ BUFFER AMPLIFIER, 7.1 - 7.9 GHz

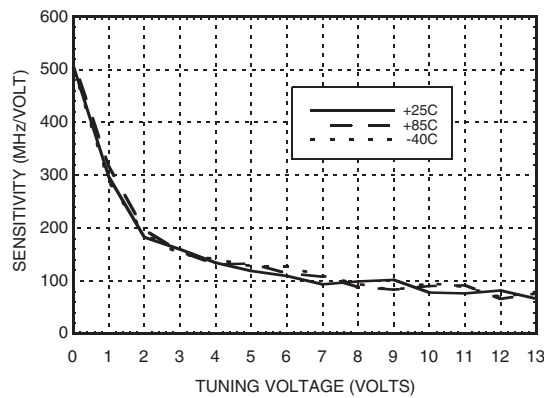
Frequency vs. Tuning Voltage, $T = 25^{\circ}\text{C}$



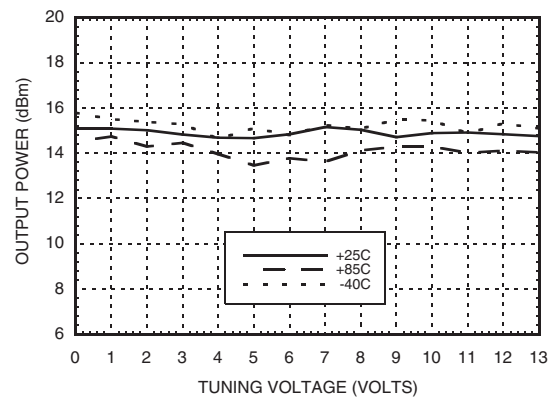
Frequency vs. Tuning Voltage, $V_{CC} = +3\text{V}$



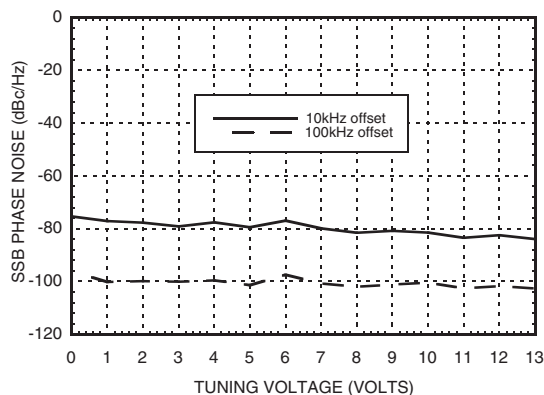
Sensitivity vs. Tuning Voltage, $V_{CC} = +3\text{V}$



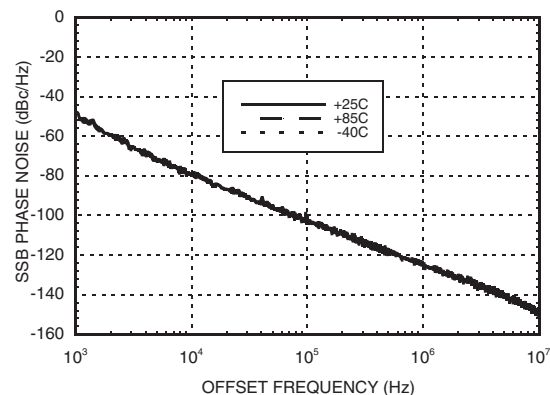
**Output Power vs.
Tuning Voltage, $V_{CC} = +3\text{V}$**



Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ $V_{\text{tune}} = +5\text{V}$



Absolute Maximum Ratings

Vcc	+3.5 Vdc
Vtune	0 to +15V
Channel Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 6.07 mW/°C above 85°C)	303 mW
Thermal Resistance (junction to ground paddle)	165 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Typical Supply Current vs. Vcc

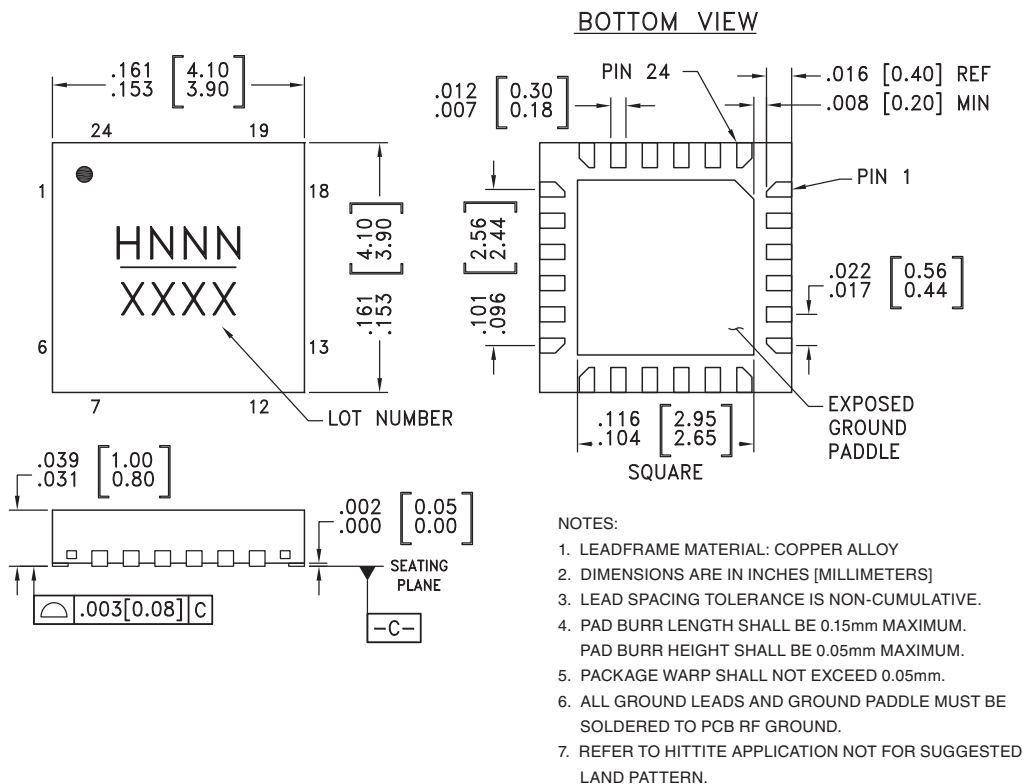
Vcc (V)	Icc (mA)
2.75	74
3.0	85
3.25	96

Note: VCO will operate over full voltage range shown above.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC532LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H532 XXXX
HMC532LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H532 XXXX


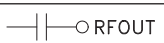
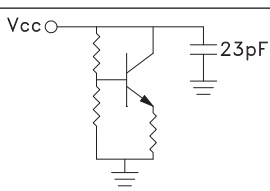
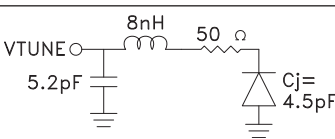
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

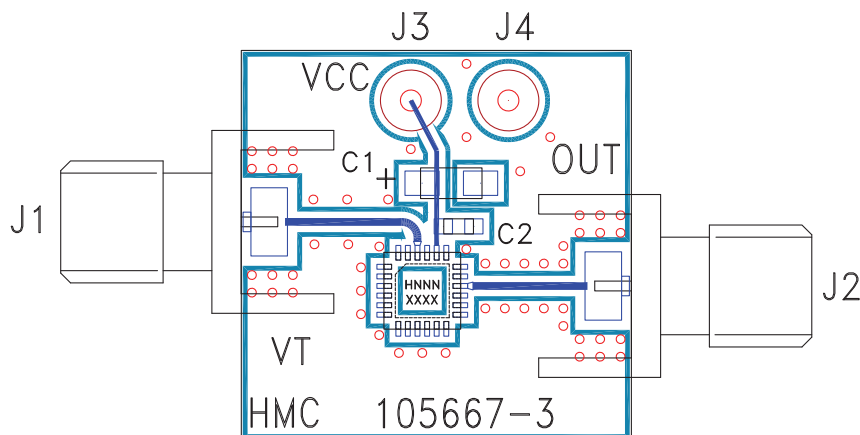
[3] 4-Digit lot number XXXX

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection	
15	GND	This pin must be connected to RF & DC ground. Package bottom has an exposed metal paddle that must be RF & DC grounded.	
16	RFOUT	RF output (AC coupled)	
20	Vcc	Supply Voltage Vcc= 3V	
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance. See "Determining the FM Bandwidth of a Wideband Varactor Tuned VCO" application note.	

Evaluation PCB



List of Materials for Evaluation PCB 105706 ^[1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J4	DC Pin
C1	4.7 μ F Tantalum Capacitor
C2	10,000 pF Capacitor, 0603 Pkg.
U1	HMC532LP4 / HMC532LP4E VCO
PCB [2]	105667 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.